Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	20	flash and memory and cell and region and STI and filler	USPAT	OR	ON	2004/11/10 15:51
L4	20	L3 and (CMP or HDP or oxide or hard or mask or EEPROM or STI or protective or periphery or removed or partialy or polysilicon or gate or IPO or LPCvD or cvd)	USPAT	OR	ON	2004/11/10 15:51
L5	1	("6403494").PN.	USPAT	OR	OFF	2004/11/10 16:11
L6	1	("6255689").PN.	USPAT	OR	OFF	2004/11/10 16:12
L7	1138	438/680	USPAT	OR	ON	2004/11/10 16:12
L8	3460874	"1"	USPAT	OR	ON	2004/11/10 16:12
L9	560	438/681	USPAT	OR	ON	2004/11/10 16:12
L10	1007	438/689	USPAT	OR	ON	2004/11/10 16:12
L11	3280	438/692	USPAT	OR	ON	2004/11/10 16:12
L12	666	438/695	USPAT	OR	ON	2004/11/10 16:13
L13	687	438/697	USPAT	OR	ON	2004/11/10 16:13
L14	1422	438/700	USPAT	OR	ON	2004/11/10 16:13
L15	1733	438/706	USPAT	OR	ON	2004/11/10 16:13
L16	237	438/733	USPAT	OR	ON	2004/11/10 16:13
L17	747	438/734	USPAT	OR	ON	2004/11/10 16:13
L18	437	438/735	USPAT	OR	ON	2004/11/10 16:13
L19	306	438/736	USPAT	OR	ON	2004/11/10 16:13
L20	390	438/744	USPAT	OR	ON	2004/11/10 16:13
L21	850	438/724	USPAT	OR	ON	2004/11/10 16:13

11/10/04